KEC

SEMICONDUCTOR
TECHNICAL DATA

KIA7019AP/AF/AT~
KIA7045AP/AF/AT
BIPOLAR LINEAR INTEGRATED CIRCUIT

VOLTAGE DETECTOR

Function of this IC is accurately resetting the system after detecting voltage at the time of switching power on and instantaneous power off in various CPU systems and other logic systems.

FEATURES

· Current Consumption is Low. I_{CCL}=300 μA Typ. I_{CCH}=30 μA Typ.
· Resetting Output Minimum Guarantee Voltage is Low 0.8V Typ.
· Hysteresis Voltage is Provided. 50mV Typ.
· Reset Signal Generation Starting Voltages :

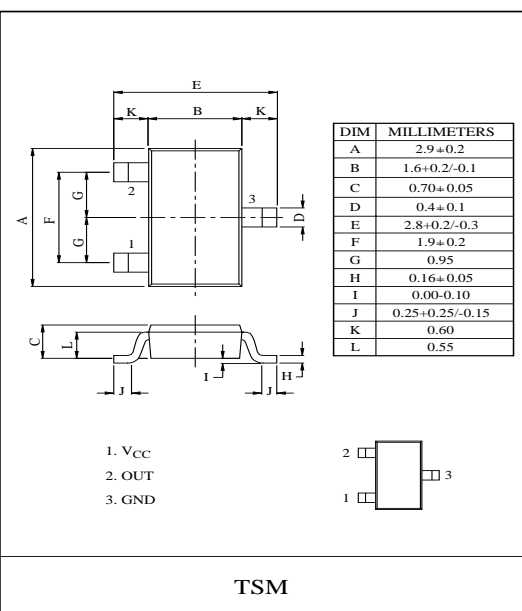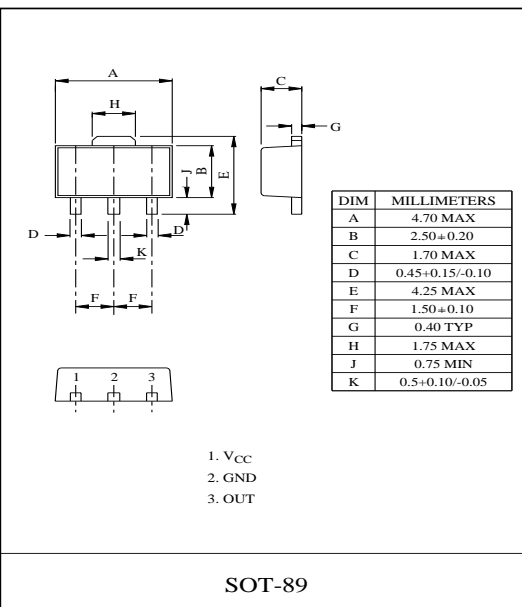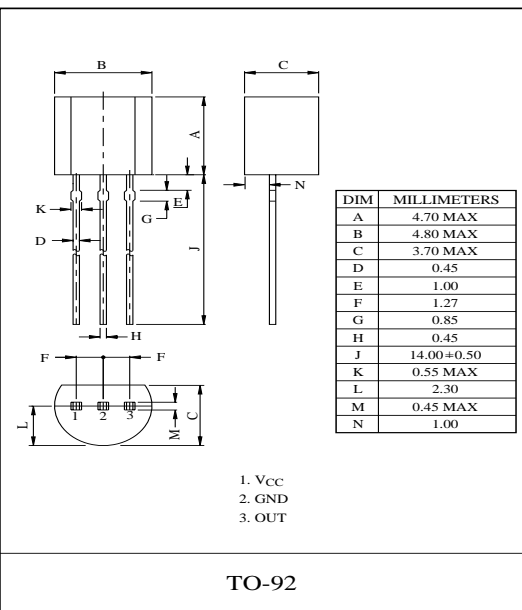|			
KIA7019	1.9V Typ.	KIA7033	3.3V Typ.
KIA7021	2.1V Typ.	KIA7034	3.4V Typ.
KIA7023	2.3V Typ.	KIA7035	3.5V Typ.
KIA7025	2.5V Typ.	KIA7036	3.6V Typ.
KIA7027	2.7V Typ.	KIA7039	3.9V Typ.
KIA7029	2.9V Typ.	KIA7042	4.2V Typ.
KIA7031	3.1V Typ.	KIA7045	4.5V Typ.
KIA7032	3.2V Typ.		

· Taping Type is also Available.

APPLICATIONS

(1) As Control Circuit of Battery-Backed Memory.
(2) As Measure Against Erroneous Operations at Power ON-OFF.
(3) As Measure Against System Runaway at Instantaneous Break of Power Supply etc.
(4) As Resetting Function for the CPU-Mounted Equipment, such as Personal Computers, Printers, VTRs and so forth.

EQUIVALENT CIRCUIT
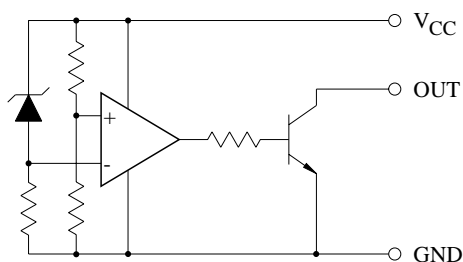
Marking

Type No.	Marking	Type No.	Marking	Type No.	Marking
KIA7019AF/AT	6A	KIA7029AF/AT	6F	KIA7035AF/AT	6L
KIA7021AF/AT	6B	KIA7031AF/AT	6G	KIA7036AF/AT	6M
KIA7023AF/AT	6C	KIA7032AF/AT	6H	KIA7039AF/AT	6N
KIA7025AF/AT	6D	KIA7033AF/AT	6J	KIA7042AF/AT	6P
KIA7027AF/AT	6E	KIA7034AF/AT	6K	KIA7045AF/AT	6R

1. V_{CC}
2. GND
3. OUT

TO-92

DIM	MILLIMETERS
A	4.70 MAX
B	4.80 MAX
C	3.70 MAX
D	0.45
E	1.00
F	1.27
G	0.85
H	0.45
J	14.00±0.50
K	0.55 MAX
L	2.30
M	0.45 MAX
N	1.00

1. V_{CC}
2. GND
3. OUT

SOT-89

DIM	MILLIMETERS
A	4.70 MAX
B	2.50±0.20
C	1.70 MAX
D	0.45+0.15/-0.10
E	4.25 MAX
F	1.50±0.10
G	0.40 TYP
H	1.75 MAX
J	0.75 MIN
K	0.5+0.10/-0.05

1. V_{CC}
2. OUT
3. GND

TSM

DIM	MILLIMETERS
A	2.9±0.2
B	1.6+0.2/-0.1
C	0.70±0.05
D	0.4±0.1
E	2.8+0.2/-0.3
F	1.9±0.2
G	0.95
H	0.16±0.05
I	0.00-0.10
J	0.25+0.25/-0.15
K	0.60
L	0.55

KIA7019AP/AF/AT~KIA7045AP/AF/AT

MAXIMUM RATINGS (Ta=25℃)

CHARACTERISTIC		SYMBOL	RATING	UNIT
Supply Voltage		V_{CC}	-0.3～+15.0	V
Power Dissipation (Package Limitation)	KIA7019AP~45AP	P_D	400	mW
	KIA7019AF~45AF		500	
	KIA7019AT~45AT		350	
Operating Temperature		T_{opr}	-30～+75	℃
Storage Temperature		T_{stg}	-55～+150	℃

ELECTRICAL CHARACTERISTICS (V_{CC}=5V, V_{EE}=GND, Ta=25℃)

CHARACTERISTIC	SYMBOL	TEST CIRCUIT	TEST CONDITION		MIN.	TYP.	MAX.	UNIT
Detecting Voltage	V_S	1	R_L=200Ω V_{OL}≦0.4V	KIA7019	1.75	1.9	2.05	V
				KIA7021	1.95	2.1	2.25	
				KIA7023	2.15	2.3	2.45	
				KIA7025	2.35	2.5	2.65	
				KIA7027	2.55	2.7	2.85	
				KIA7029	2.75	2.9	3.05	
				KIA7031	2.95	3.1	3.25	
				KIA7032	3.05	3.2	3.35	
				KIA7033	3.15	3.3	3.45	
				KIA7034	3.25	3.4	3.55	
				KIA7035	3.35	3.5	3.65	
				KIA7036	3.45	3.6	3.75	
				KIA7039	3.75	3.9	4.05	
				KIA7042	4.05	4.2	4.35	
				KIA7045	4.35	4.5	4.65	
Low-Level Output Voltage	V_{OL}	1	R_L=200Ω		-	-	0.4	V
Output Leakage Current	I_{OH}	1	V_{CC}=15V		-	-	0.1	μA
Hysteresis Voltage	⊿Vs	1	R_L=200Ω		30	50	100	mV
Detecting Voltage Temperature Coefficient	Vs/⊿T	1	R_L=200Ω		-	±0.01	-	%/℃
Circuit Current at on Time	IccL	1	V_{CC}=Vsmin.-0.05V		-	300	500	μA
Circuit Current at off Time	IccH	1	V_{CC}=5.25V		-	30	50	μA
Threshold Operating Voltage	Vopr	1	R_L=200Ω, V_{OL}≦0.4V		-	0.8	-	V
"L" Transmission Delay Time	tpHL	2	R_L=1.0kΩ, C_L=100pF		-	10	-	μs
"H" Transmission Delay Time	tpLH	2	R_L=1.0kΩ, C_L=100pF		-	15	-	μs
Output Current at on Time I	IoL I	1	V_{CC}=Vsmin.-0.05V, Tc=25℃		20	-	-	mA
Output Current at on Time II	IoL II	1	V_{CC}=Vsmin.-0.05V, Tc=-30～+75℃		16	-	-	mA
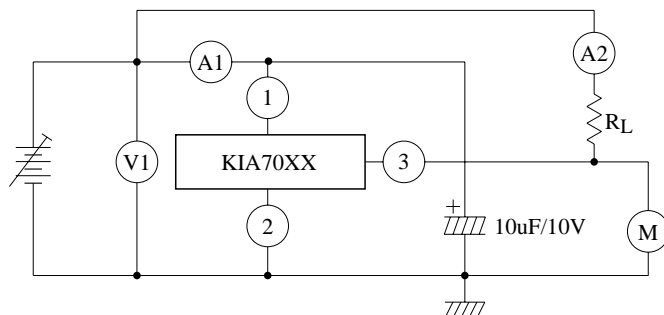
TEST CIRCUIT 1.
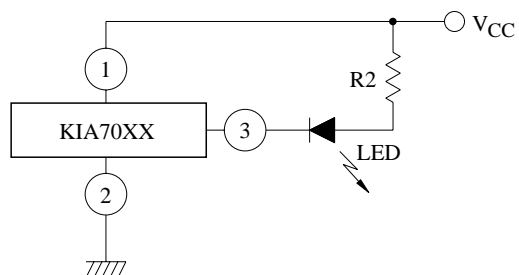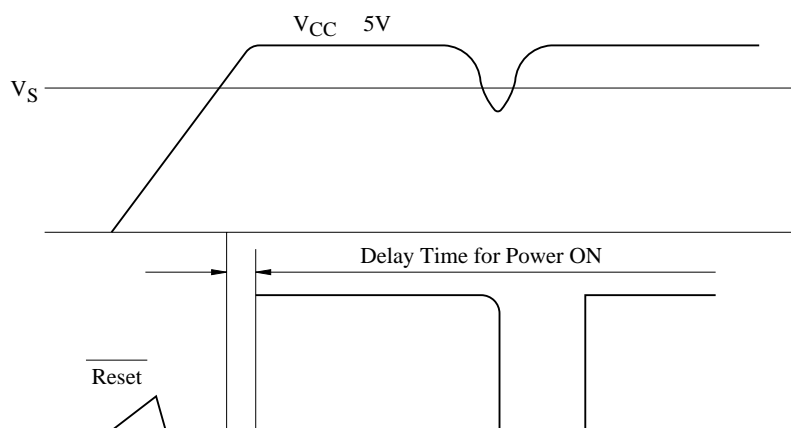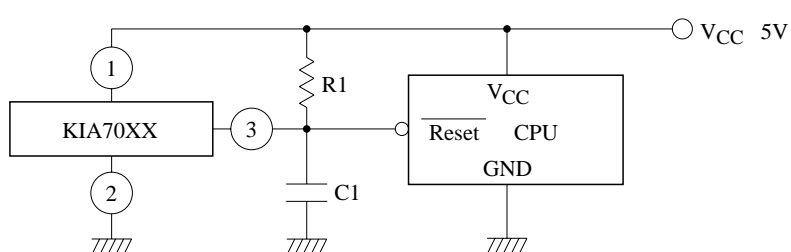

TEST CIRCUIT 2.
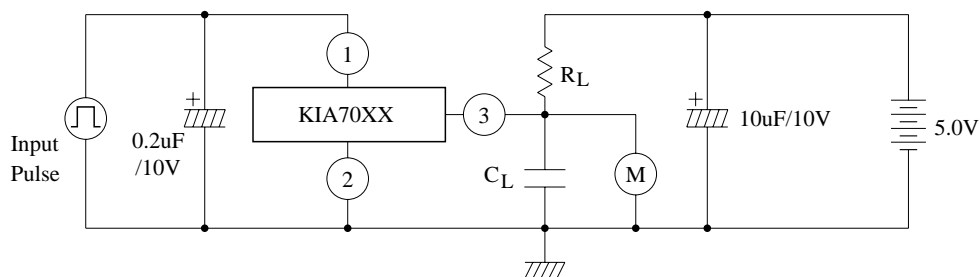
APPLICATION CIRCUIT

(1) BATTERY LOW INDICATOR   (2) CPU RESETTING

(NOTE)

(1) Connecting of LED and R2 obtains a voltage drop indicator.

(2) Connecting of C1 and selection of time constant with C1 and R1 set

the power on delay time.

PRECAUTION FOR USE

SOLDERING

Flat Package (SOT-89 Package)

   Elements mounting styles of electronic devices are gaining in further diversification over recent years, and needs for components are all the more expanding in varieties. Especially, surface mounting is steadily penetrating into industrial segments as a world-wide popular technical trend. Although exposure to high temperature is inevitable during soldering we recommend limiting the soldering temperature to low levels as shown in figure for the sake of retaining inherent excellent reliability.
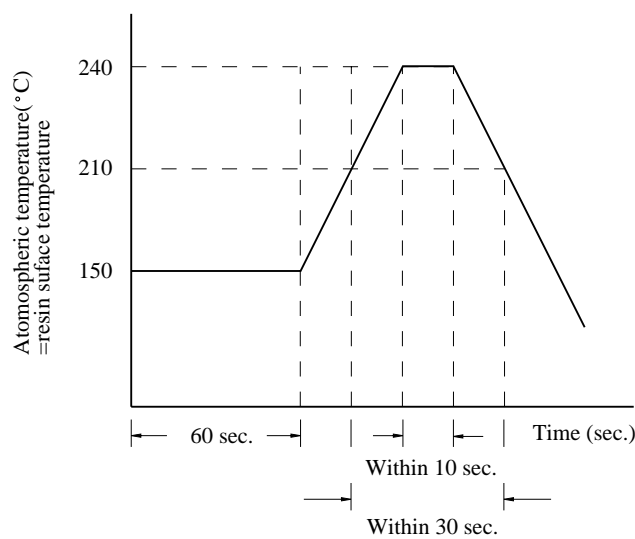

Fig   6

(a) When employing solder reflow method

   ① Atmospheric temperature around resin surfaces must be less than 240℃, not exceeding the time length of 10 sec.

   ② Recommend temperature profile

   ③ Precautions on heating method

      When resin in kept exposed to high temperature for a long time, device reliability may be marred.

      Therefore, it is essential to complete soldering in the shortest time possible to prevent temperature of resin from rising.

(b) When employing halogen lamps or infrared-ray heaters

   When halogen lamps or infrared-ray heaters are used, avoid direct irradiation onto resin surfaces; such devices cause extensive localized temperature rise.

※ Please keep a reflow solder operating when SOT-89 package's soldering.